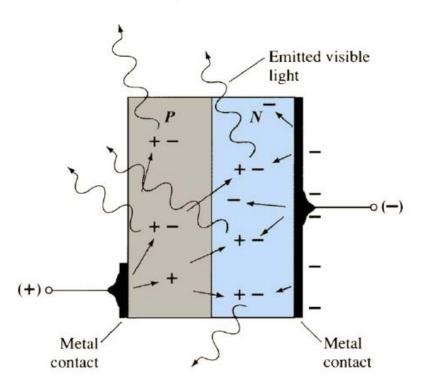
Parte C

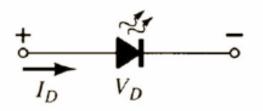
Diodos

LEDs

Diodos emissores de luz (LEDs):

 Eletroluminescência – processo de emissão de luz pela aplicação de uma fonte elétrica de energia.





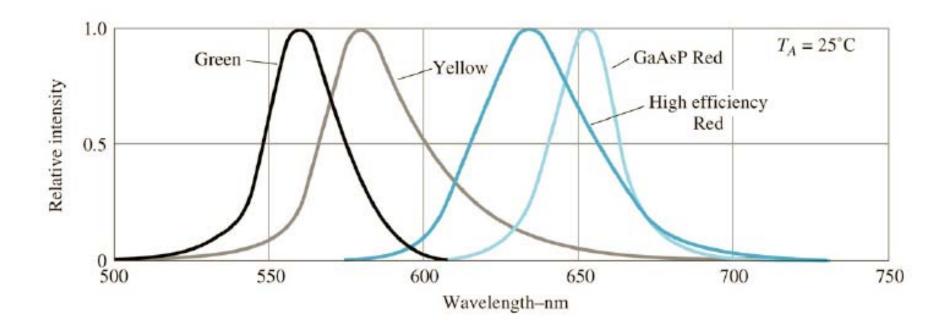






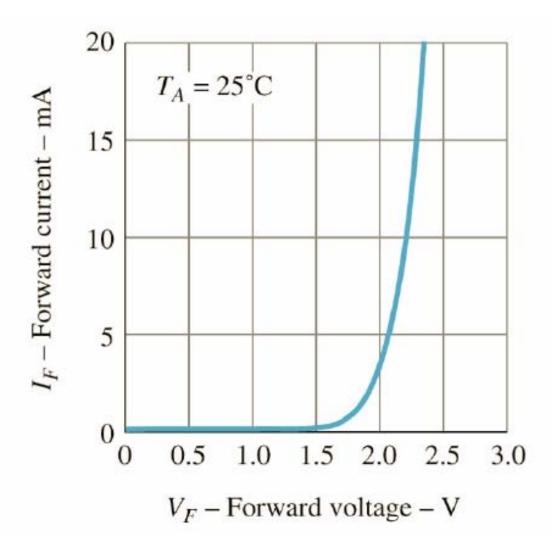


Comprimentos de onda dos leds:





Corrente direta versus tensão direta para leds miniatura:

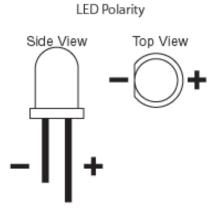




Exercícios:

Dimensionar circuitos com LED conforme especificações de

fabricantes.





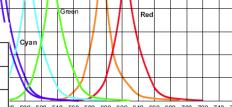
Spec	Value
Product ID	L4-0-Y5TH30-1
Angle	30
Package	5mm
Color	
Peak Wavelength in nm	590
Luminous Intensity	5000mcd typ. @ 20mA
Max Forward Current	30mA
Max Forward Current Pulse	100mA for <= 10ms, duty <= 1/10
Forward Voltage	2.25V typ. 2.6V max @ 20mA
Max Reverse Voltage	5V
Power Dissipation	
Operating Temp	-30 to +85 C
Soldering Temp	260 C for 5 Sec.
Max Reverse Current	10uA @ 5V ELETRICII

http://www.ledsupply.com

LEDs

SPECIFICATIONS FOR UPEC POWER LIGHT SOURCE TYPE LED

(%) August Pure Blue

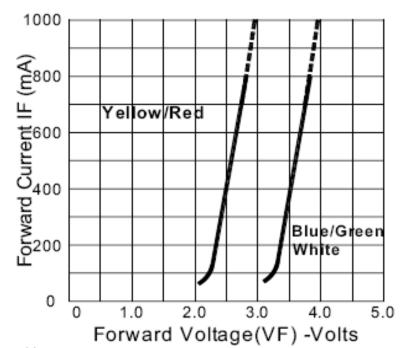


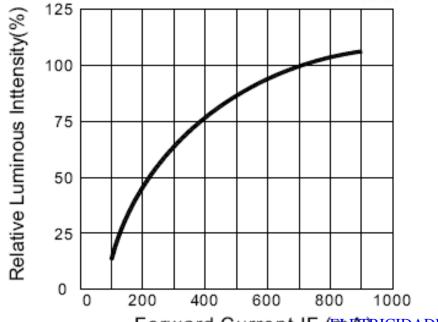
Wavelength	(1

4	Absol	ute	Maximum	Ratings	at	Ta=25°C	

Parameter	Symbol	Max	Unit
Power Dissipation	PD	3	W
Pulse Forward Current	IPF	1000	mA
Forward Current	IF	700	mA
Reverse Voltage	VR	5	٧
Operating Temperature Range	Topr	- 40 to +85	$^{\circ}$ C
Storage Temperature Range	Tstg	- 40 to + 85	°C







Forward Current IF (PA)RICIDADE -6/20.

http://www.u-pec.com



SPECIFICATIONS FOR UPEC LTCC LIGHT SOURCE LED

MAXIMUM RATINGS

Parameter	Symbol		Values		I I mi 4
i arameter	Symbol	Red Pure G	Pure Green	Blue	Unit
Operating temperature range	Тор		-40 + 85		°C
Storage temperature range	Tstg	-40 +100			$^{\circ}\! \mathbb{C}$
Power dissipation (Max)	Pd	2			W
Pulse forward current per chip	lpf	250	300	250	mA
Forward current (R,G,B)	lf	150	200	150	mA
Test current (White mixed)	lf	100	200	50	mA
Reverse voltage	Vr	5			V



CHARACTERISTICS (T_J = 25 °C)

Parameter	Symbol		Values		Unit	
Farameter	Symbol	Red	Pure Green	Blue	Offic	
Dominant wavelength	λdom	620~630	520~530	455~465	nm	
Spectral bandwidth at 50 % (Typ)	Δλ	20	30	20	nm	
Viewing angle at 50% l∨	2θ _{1/2}	120	120	120	deg.	
Forward voltage	Vf	2.0	2.8	2.8	٧	
		3.0	3.6	3.6		
Reverse current	lr		100		μA	

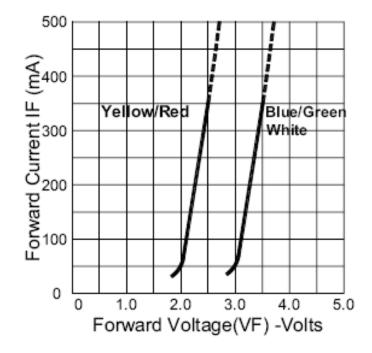
LEDs

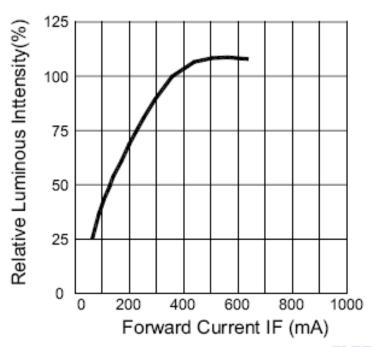
SPECIFICATIONS FOR UPEC LED LIGHT SOURCE TYPE SYSTEM

Absolute Maximum Ratings at Ta=25℃

Parameter	Symbol	Max	Unit
Power Dissipation	PD	6	W
Pulse Forward Current	IPF	500	mA
Forward Current	IF	350	mA
Operating Temperature Range	Topr	- 40 to + 120	°C
Storage Temperature Range	Tstg	- 40 to + 120	°C







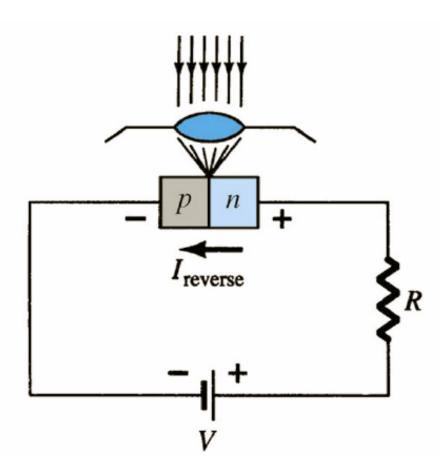
ELETRICIDADE -8/20.

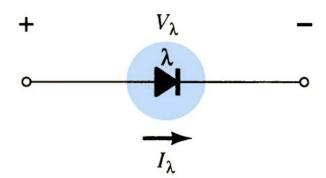
Fotodiodos:

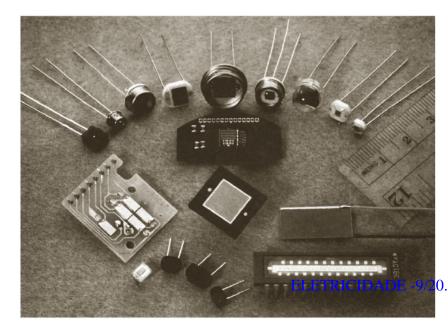
São diodos que operam na região reversa e são sensíveis à luz.

Optoeletrônica – campo de estudo dos dispositivos sensíveis à

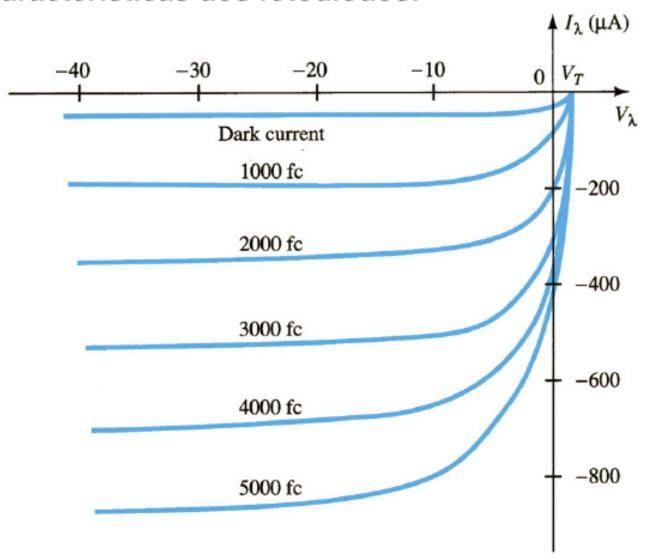
luz.





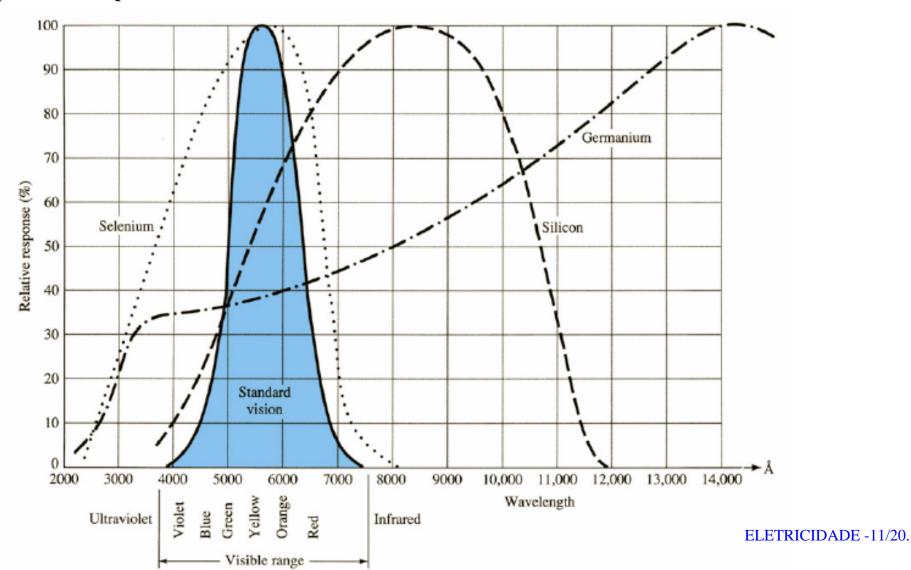


Curvas características dos fotodiodos:

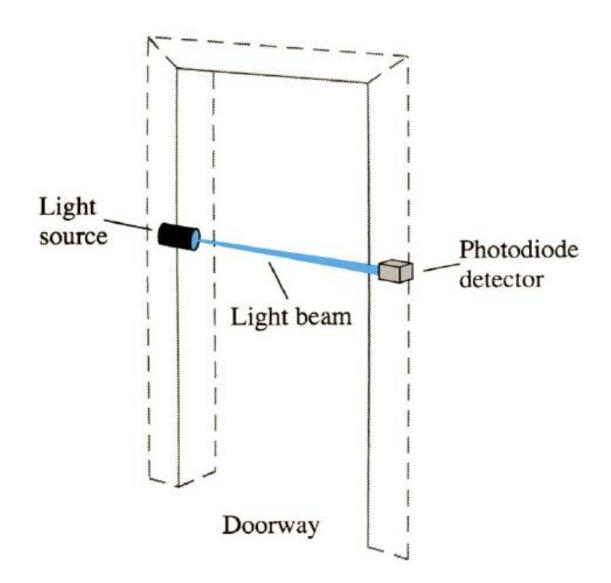


ELETRICIDADE -10/20.

Resposta espectral de fotodiodos:



Exemplo de aplicação:



ELETRICIDADE -12/20.

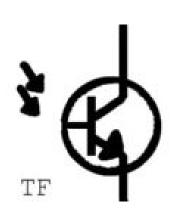
Parte D

Transistores

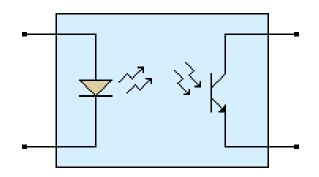
Fototransistor

Fototransistor:

São transistores sensíveis à luz.









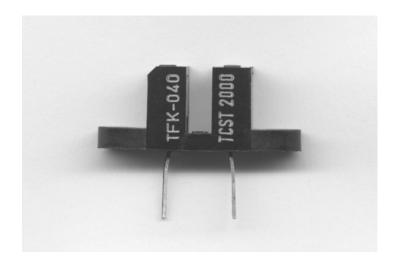


Optoacopladores

Optoacoplador:

- São dispositivos que possuem no mesmo encapsulamento um fotodiodo e um fototransistor (ou tiristor), montados de maneira a permitirem o acoplamento óptico entre os dois.
- Usados para isolação entre circuitos, pois não ocorre ligação elétrica entre os circuitos, por exemplo para transmissão de dados.



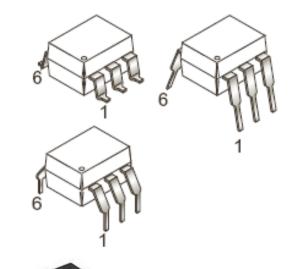


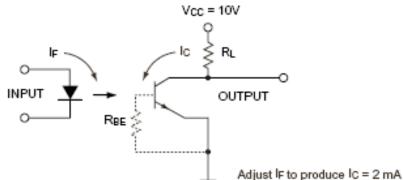


Optoacopladores

FAIRCHILD

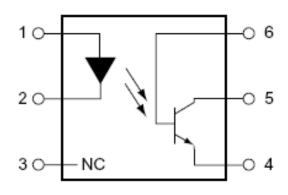
4N25M, 4N26M, 4N27M, 4N28M, 4N35M, 4N36M, 4N37M, H11A1M, H11A2M, H11A3M, H11A4M, H11A5M General Purpose 6-Pin Phototransistor Optocouplers





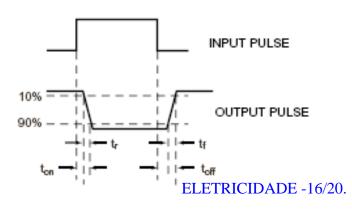
TEST CIRCUIT

March 2007



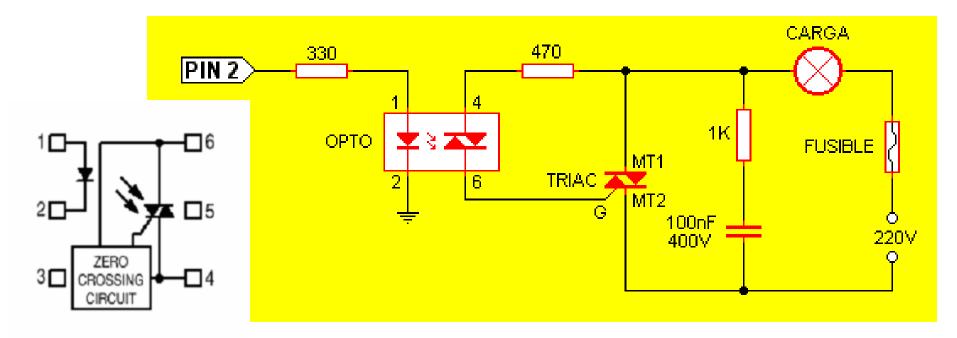
- PIN 1. ANODE
 - 2. CATHODE
 - 3. NO CONNECTION
 - 4. EMITTER
 - 5. COLLECTOR
 - 6. BASE

WAVE FORMS

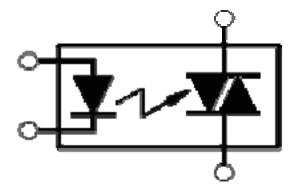


Optoacopladores

Optoacoplador com saída tiristorizada:



- 1. ANODE
- 2. CATHODE
- 3. NC
- 4. MAIN TERMINAL
- SUBSTRATE DO NOT CONNECT
- 6. MAIN TERMINAL



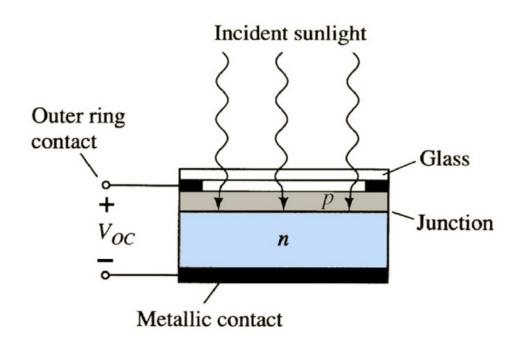
Outros dispositivos

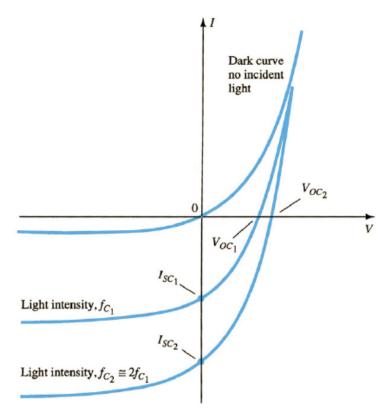
Células solares

Células solares

Células solares:

- São dispositivos construídos a partir de materiais semicondutores e que são sensíveis à luz.
- Geram potências da ordem de mW quando iluminados.





Células solares

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